NSN 5962-01-135-2111

Memory Microcircuit - Page 1 of 2

Yes - demil/mli



View Online at https://aerobasegroup.com/nsn/5962-01-135-2111

Body Length:	
1.310 inches	
Body Width:	
0.600 inches	
Body Height:	
0.052 inches	
Maximum Power Dissipation	on Rating:
400.0 milliwatts	
Operating Tempurature Ra	ange:
+0.0/+75.0 degrees celsius	
Storage Tempurature Rang	ge:
-65.0/+150.0 degrees celsius	s
End Application:	
Training dev 08783	
Features Provided:	
Hermetically sealed and pro	grammable and expandable and wire-or outputs and w/enable
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
8 input	
Terminal Surface Treatment	nt:
Solder	
Voltage Rating And Type F	Per Characteristic:
-1.5 volts power source and	5.5 volts power source
Time Rating Per Chacteris	tic:
75.00 nanoseconds propag	ation delay time, low to high level output
Memory Device Type:	
Rom	
Memory Capacity:	
Unknown	
Terminal Type And Quanti	ty:
24 printed circuit	
Shelf Life:	
N/a	

NSN 5962-01-135-2111

Memory Microcircuit - Page 2 of 2

Fiig: A458a0

